

Features

- Heat transfer through aluminium nitride ceramic isolated metal baseplate
- Precious metal pressure contacts for high reliability
- Thyristor with amplifying gate

Typical Applications

- DC motor control
- Temperature control
- Professional light dimming

Maximum Ratings

Symbol	Condition	Ratings	Unit
I _{T(AV)M}	Single phase, half wave, sin 180° conduction ; T _C =85°C	320	A
I _{TRMSM}	Single phase, half wave, sin 180° conduction	520	A
I _{TSM}	T _j = T _j MAX	8.2	kA
I ² t	T _j = T _j MAX	335	kA ² S
V _{DRM} /V _{RRM}	T _j = T _j MAX	1600	V
di/dt	non-repetitive	100	A/us
V _{iso}	A.C.1minute/1S	3000/3600	V
T _j		-40 ~ + 130	°C
T _{stg}		-40 ~ + 130	°C
W	About	410	g

Electrical Characteristics

Symbol	Condition	Ratings	Unit
I _{DRM} /I _{RRM}	At V _{DRM} , Single phase, half wave, T _j = T _j MAX	60	mA
V _{TM}	On-State Current 750A, T _j =130°C	1.47	V
V _{T(TO)}	T _j = T _j MAX	0.77	V
r _T	T _j = T _j MAX	0.58	mΩ
R _{K1G1}		-	Ω
R _{K2G2}		-	Ω
t _{gd}	T _j =25°C; V _D =0.4V _{DRM} ; I _{TM} =I _{TAV}	2	us
t _q	dV _D /dt=50V/us; T _j = T _j MAX; I _{TM} =I _{TAV}	200	us
I _{GT} /V _{GT}	T _j =25°C, I _T =1A, V _D =6V	150 / 2.0	mA/V
V _{GD}	V _D =67%V _{DRM}	0.25	V
DV/DT	V _D =67%V _{DRM}	1000	V/us
I _H	T _j =25°C	150	mA
I _L	T _j =25°C	380	mA
R _{th(j-c)}	Thermal resistance Junction to case; per module	0.055	K/W
R _{th(c-h)}	Thermal resistance case to heatsink; per module	0.0275	K/W

TYPE: TT320N16SOF

Outline Drawing

